

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013 PHONE: (215) 631-9840 FAX: (215) 631-9855

MS2361 RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS Features DESIGNED FOR HIGH POWER PULSED IFF, DME, • **TACAN, APPLICATIONS** 80 WATTS (typ.) IFF 1030 – 1090 MHz 75 WATTS (min.) DME 1025 - 1150 MHz • 50 WATTS (typ.) TACAN 960 - 1215 MHz • .280 4LSL (M115) 7.6 dB MIN. GAIN epoxy sealed **REFRACTORY GOLD METALLIZATION** EMITTER BALLASTING AND LOW THERMAL **RESISTANCE FOR RELIABILITY AND RUGGEDNESS INFINITE LOAD VSWR CAPABILITY AT SPECIFIED OPERATING CONDITIONS PIN CONNECTION** INPUT MATCHED, COMMON BASE CONFIGURATION

DESCRIPTION:

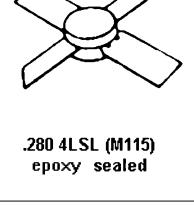
The MS2361 is a gold metallized silicon, NPN power transistor designed for applications requiring high peak power and low duty cycles such as IFF, DME and TACAN. The MS2361 is packaged in the 0.280" input matched stripline package resulting in improved broadband performance and a low thermal resistance.

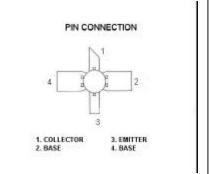
ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	65	V
V _{CES}	Collector-Emitter Voltage	65	V
V _{EBO}	Emitter-Base Voltage	3.5	V
Ιc	Device Current	5.5	Α
P _{DISS}	Power Dissipation	218.7	W
TJ	Junction Temperature	+200	°C
Т _{stg}	Storage Temperature	-65 to +150	°C

Thermal Data

R _{TH(J-C)} Junction-case Thermal Resistance	0.8	°C/W
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MS2361

ELECTRICAL SPECIFICATIONS (Tcase = 25° C)

STATIC

Symbol	Test Conditions		Value		Unit	
Symbol			Min.	Тур.	Max.	Unit
BV _{CBO}	l _c = 10mA	I _E = 0mA	65			v
BV _{CES}	I _C = 25mA	$V_{BE} = 0V$	65			v
BV _{EBO}	I _E = 10mA	I _c = 0mA	3.5			v
I _{CES}	V _{CE} = 50V	I _E = 0mA			5	mA
h _{FE}	$V_{CE} = 5V$	I _C = 100mA	10			

DYNAMIC

Symbol	Symbol Test Conditions		Value		
Symbol			Тур.	Max.	Unit
Pout	f =1025 - 1150 MHz P_{IN} = 13.0W V_{CE} = 50V	75			W
G _P	f =1025 - 1150 MHz P_{IN} = 13.0W V_{CE} = 50V	7.6			dB

Note: Pulse Width = 10us, Duty Cycle = 1%

This device is suitable for use under other pulse width/duty cycle conditions. Please contact the factory for specific application assistance.

IMPEDANCE DATA

FREQ	Z _{IN} (Ω)	Ζ_{CL} (Ω)
960 MHz	2.5 + j 13.0	4.6 + j 5.5
1030 MHz	5.2 + j 15.0	5.0 + j 5.5
1090 MHz	16.3 + j 15.0	4.8 + j 5.5
1150 MHz	14.7 + j 2.5	4.7 – j 7.0
1215 MHz	7.6 + j 0.5	4.7 – j 5.0

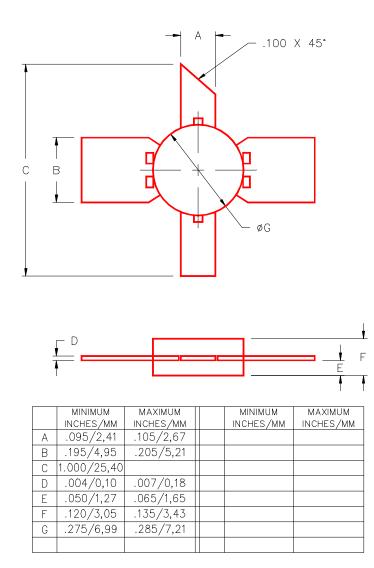
 $\begin{array}{l} P_{\text{IN}} = 13W \\ V_{\text{CC}} = 50V \\ \text{Pulse Width} = 10u\text{Sec} \\ \text{Duty Cycle} = 1\% \end{array}$



MS2361

PACKAGE MECHANICAL DATA

PACKAGE STYLE M115



Advanced Power Technology reserves the right to change, without notice, the specifications and information contained herein Visit our website at **WWW.ADVANCEDPOWER.COM** or contact our factory direct.